

Phase Control Thyristors (Hockey PUK Version), 500 A



PRIMARY CHARACTERISTICS					
I _{T(AV)} 500 A					
V _{DRM} /V _{RRM}	400 V, 600 V				
V_{TM}	1.36 V				
I _{GT}	90 mA				
TJ	-40 °C to +125 °C				
Package	A-PUK (TO-200AB)				
Circuit configuration	Single SCR				

FEATURES

- · Center amplifying gate
- Metal case with ceramic insulator
- International standard case A-PUK (TO-200AB))



- Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

TYPICAL APPLICATIONS

- DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS						
PARAMETER	TEST CONDITIONS	VALUES	UNITS			
		500	А			
$I_{T(AV)}$	T _{hs}	55	°C			
I		960	Α			
I _T (RMS)	T _{hs}	25	°C			
1	50 Hz	7850	A			
I _{TSM}	60 Hz	8220	^			
l ² t	50 Hz	308	kA ² s			
1-1	60 Hz	281	KA-S			
V _{DRM} /V _{RRM}		400 to 600	V			
t _q	Typical	100	μs			
T _J		- 40 to 125	°C			

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS								
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	$\begin{split} I_{DRM}/I_{RRM} & \text{MAXIMUM AT} \\ T_J &= T_J & \text{MAXIMUM} \\ & \text{mA} \end{split}$				
ST280CC	04	400	500	30				
3120000	06	600	700	30				



PARAMETER PARAMETER	SYMBOL		TEST CONDITIONS			UNITS
Maximum average on-state current		180° condu	180° conduction, half sine wave			A
at heatsink temperature	$I_{T(AV)}$		(single side) cod		55 (85)	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 25 °C	DC at 25 °C heatsink temperature double side cooled			
		t = 10 ms	No voltage		7850	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		8220	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}	Sinusoidal half wave, initial $T_J = T_J$ maximum	6600	
		t = 8.3 ms	reapplied		6900	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage		308	
		t = 8.3 ms	reapplied		281	
		t = 10 ms	100 % V _{RRM}		218	
		t = 8.3 ms	reapplied		200	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	t = 0.1 to 10 ms, no voltage reapplied			kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)})$	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			ľ
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)} < I < \pi$ x $I_{T(AV)}$), $T_J = T_J$ maximum			0.50	mΩ
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$			0.47	11177
Maximum on-state voltage	V_{TM}	$I_{pk} = 1050 \text{ A}, T_J = 125 \text{ °C}, t_p = 10 \text{ ms sine pulse}$			1.36	V
Maximum holding current	I _H	T _ 05 °C	T 0500 and a col 40 / model at		600	mA
Maximum (typical) latching current	ΙL	T _J = 25 °C, anode supply 12 V resistive load		1000 (300)		

SWITCHING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum non-repetitive rate of rise of turned-on current	dl/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs		
Typical delay time	t _d	Gate current 1 A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 \ ^{\circ}C$	1.0			
Typical turn-off time	tq	I_{TM} = 300 A, T_J = T_J maximum, dl/dt = 20 A/μs, V_R = 50 V, dV/dt = 20 V/μs, gate 0 V 100 Ω , t_p = 500 μs	100	μs		

BLOCKING						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum critical rate of rise of off-state voltage	dV/dt	T _J = T _J maximum linear to 80 % rated V _{DRM}	500	V/µs		
Maximum peak reverse and off-state leakage current	I _{RRM} , I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	30	mA		



TRIGGERING							
PARAMETER	SYMBOL	TE			VALUES		
PARAMETER	STIVIBUL	15	ST CONDITIONS	TYP.	MAX.	UNITS	
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	$t_p \le 5 \text{ ms}$	10	0.0	W	
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	v	
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	$t_p \leq 5 \ ms$	3	.0	Α	
Maximum peak positive gate voltage	+ V _{GM}	$T_J = T_J$ maximum, $t_p \le 5$ ms		M 20		0	V
Maximum peak negative gate voltage	- V _{GM}	rj = rj maximum,	5.0]		
DC gate current required to trigger	I _{GT}	T _J = - 40 °C	Maximum required gate trigger/ current/voltage are the lowest	180	-	mA	
		T _J = 25 °C		90	150		
		T _J = 125 °C		40	-		
		T _J = - 40 °C	value which will trigger all units 12 V anode to cathode applied	2.9	-		
DC gate voltage required to trigger	V _{GT}	T _J = 25 °C	12 v anode to cathode applied	1.8	3.0	V	
		T _J = 125 °C		1.2	-		
DC gate current not to trigger	I _{GD}	T T	Maximum gate current/voltage not to trigger is the maximum value which will not trigger any unit with rated V _{DRM} anode to cathode applied	10		mA	
DC gate voltage not to trigger	V_{GD}	$T_J = T_J \text{ maximum}$		0.30		V	

THERMAL AND MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS		
Maximum operating junction temperature range	TJ		- 40 to 125	°C		
Maximum storage temperature range	T _{Stg}		- 40 to 150			
Maximum thermal resistance, junction to heatsink	R _{thJ-hs}	DC operation single side cooled	0.17			
		DC operation double side cooled	0.08	K/W		
Maximum thermal resistance,	R _{thC-hs}	DC operation single side cooled	0.033	I NVVV		
case to heatsink		DC operation double side cooled	0.017			
Mounting force, ± 10 %			4900 (500)	N (kg)		
Approximate weight			50	g		
Case style		See dimensions - link at the end of datasheet	A-PUK (TO-200	AB)		

△R _{thJC} CONDUCTION								
CONDUCTION ANGLE	SINUSOIDAL	CONDUCTION	RECTANGULAR	RCONDUCTION	TEGT COMPLETIONS	LIMITO		
CONDUCTION ANGLE	SINGLE SIDE	DOUBLE SIDE	SINGLE SIDE	DOUBLE SIDE	TEST CONDITIONS	UNITS		
180°	0.016	0.016	0.011	0.011	$T_J = T_J$ maximum	K/W		
120°	0.019	0.019	0.019	0.019				
90°	0.024	0.024	0.026	0.026				
60°	0.035	0.035	0.036	0.037				
30°	0.060	0.060	0.060	0.061				

Note

[•] The table above shows the increment of thermal resistance R_{thJC} when devices operate at different conduction angles than DC

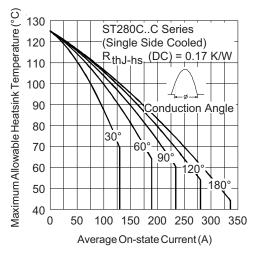


Fig. 1 - Current Ratings Characteristics

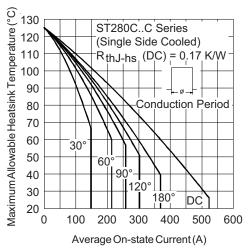


Fig. 2 - Current Ratings Characteristics

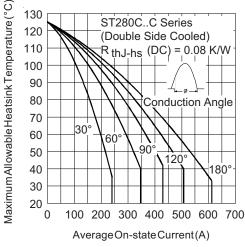


Fig. 3 - Current Ratings Characteristics

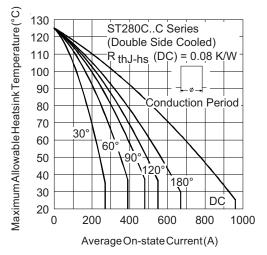


Fig. 4 - Current Ratings Characteristics

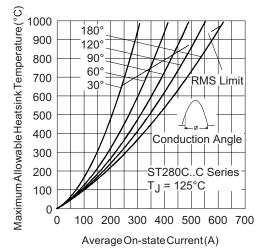


Fig. 5 - On-State Power Loss Characteristics

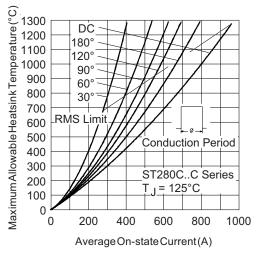


Fig. 6 - On-State Power Loss Characteristics

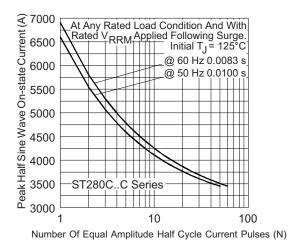


Fig. 7 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

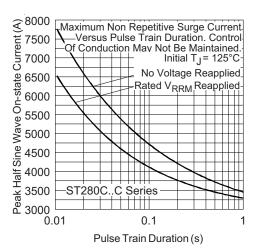


Fig. 8 - Maximum Non-Repetitive Surge Current Single and Double Side Cooled

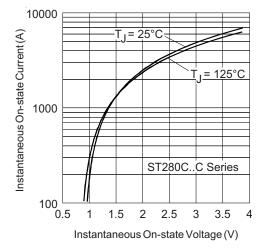


Fig. 9 - On-State Voltage Drop Characteristics

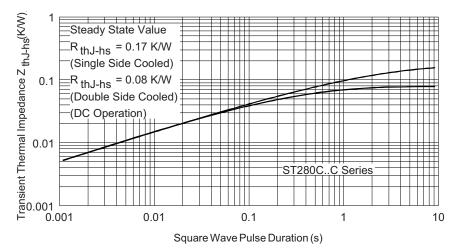


Fig. 10 - Thermal Impedance Z_{thJ-hs} Characteristics

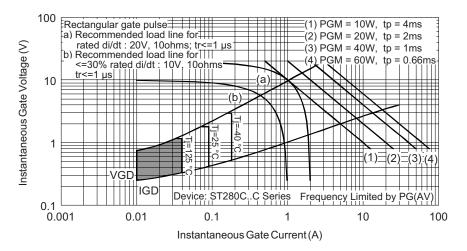
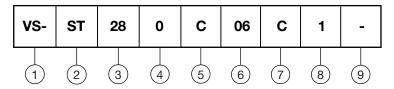


Fig. 11 - Gate Charactersitics

ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Thyristor

3 - Essential part number

4 - 0 = converter grade

5 - C = ceramic PUK

- Voltage code: code x 100 = V_{RRM} (see Voltage Ratings table)

7 - C = PUK case A-PUK (TO-200AB)

8 - 0 = eyelet terminals (gate and auxiliary cathode unsoldered leads)

1 = fast-on terminals (gate and auxiliary cathode unsoldered leads)

2 = eyelet terminals (gate and auxiliary cathode soldered leads)

3 = fast-on terminals (gate and auxiliary cathode soldered leads)

9 - Critical dV/dt: • None = 500 V/µs (standard selection)

• L = 1000 V/µs (special selection)

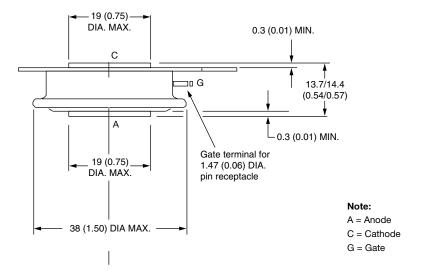
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95074			

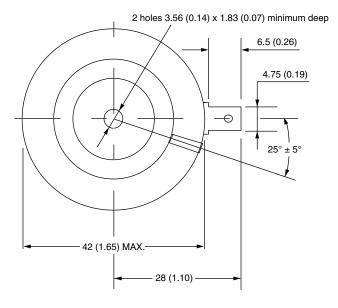


A-PUK (TO-200AB)

DIMENSIONS in millimeters (inches)

Anode to gate Creepage distance: 7.62 (0.30) minimum Strike distance: 7.12 (0.28) minimum





Quote between upper and lower pole pieces has to be considered after application of mounting force (see thermal and mechanical specification)

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